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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE Docket No.: AMD-H0634

The by certify the transmittal of the below described document is being deposited with the United States Postal Service in an envelope bearing Program is Postage and addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the below date of deposit. Name of Person Making the Deposit: Signature of the Persor Making the Deposit: Shannon Carmo Deposit: Inventor(s): Shenging FANG Serial No .: Group Art Unit: 10/661,720 2818 Filed: 09/11/2003 Examiner: Confirmation No: 8251 Title: FLASH MEMORY CELL DRAIN AND SOURCE FABRICATION METHOD AND SYSTEM Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 Sir: TRANSMITTAL OF FORMAL DRAWINGS In response to Drawing Informalities attached please find: the formal drawings for this application Number of Sheets Each sheet of drawing indicates the identifying indicia suggested in § 1.84(c) on the reverse side of the drawing a copy of the NOTICE OF INFORMAL DRAWINGS Please direct all correspondence concerning the above-identified application to the following address: WAGNER, MURABITO & HAO LLP Two North Market Street, Third Floor San Jose, California 95113 (408) 938-9060 Customer Number: 45592 Respectfully submitted, Date: October 7, 2004

Reg. No. 47,050

John F. Ryan